

Description

The AOD442G uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

V_{DS} = 60V I_D =50 A

 $R_{DS(ON)} < 17m\Omega @ V_{GS}=10V$

Application

Battery protection

Load switch

Uninterruptible power supply

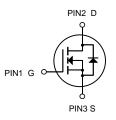
Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
AOD442G	TO-252-2L	HXY MOSFET	2500

Absolute Maximum Ratings (Tc=25°Cunless otherwise noted)

Symbol	Parameter	Rating	Units
VDS	Drain-Source Voltage	60	V
Vgs	Gate-Source Voltage	±20	V
I₀@Tc=25°C	Continuous Drain Current, V _{GS} @ 10V ¹	50	A
I _D @T _C =100°C	Continuous Drain Current, V _{GS} @ 10V ¹) 10V ¹ 38	
Ідм	Pulsed Drain Current ²	180	А
EAS	Single Pulse Avalanche Energy ³	280	mJ
las	Avalanche Current	e Current 28	
P₀@Tc=25°C	Total Power Dissipation ⁴	87.7	W
Тѕтс	Storage Temperature Range	-55 to 150	°C
TJ	Operating Junction Temperature Range	-55 to 150	°C
R _θ JA	Thermal Resistance Junction-Ambient ¹	62	°C/W





N-Channel MOSFET



Electrical Characteristics (T_c=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	·			•		
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	60	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250µA	1.0	1.5	2.5	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =30A	-	13	17	mΩ
Forward Transconductance	g _{FS}	V _{DS} =5V,I _D =30A	30	-	-	S
Dynamic Characteristics (Note4)			1			
Input Capacitance	C _{lss}		-	2498	-	PF
Output Capacitance	Coss	$V_{DS}=25V, V_{GS}=0V,$	-	185	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	80	-	PF
Switching Characteristics (Note 4)			1			
Turn-on Delay Time	t _{d(on)}		-	12	-	nS
Turn-on Rise Time	tr	V_{DD} =30V, I_{D} =2A, R_{L} =1 Ω	-	5.2	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{GEN} =3 Ω	-	38	-	nS
Turn-Off Fall Time	t _f		-	27	-	nS
Total Gate Charge	Qg	N/ 001/1 001	-	36	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =30V,I _D =30A,	-	9.9	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	6.6	-	nC
Drain-Source Diode Characteristics			1			
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =30A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	58	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF =30A	-	35		nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	47		nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

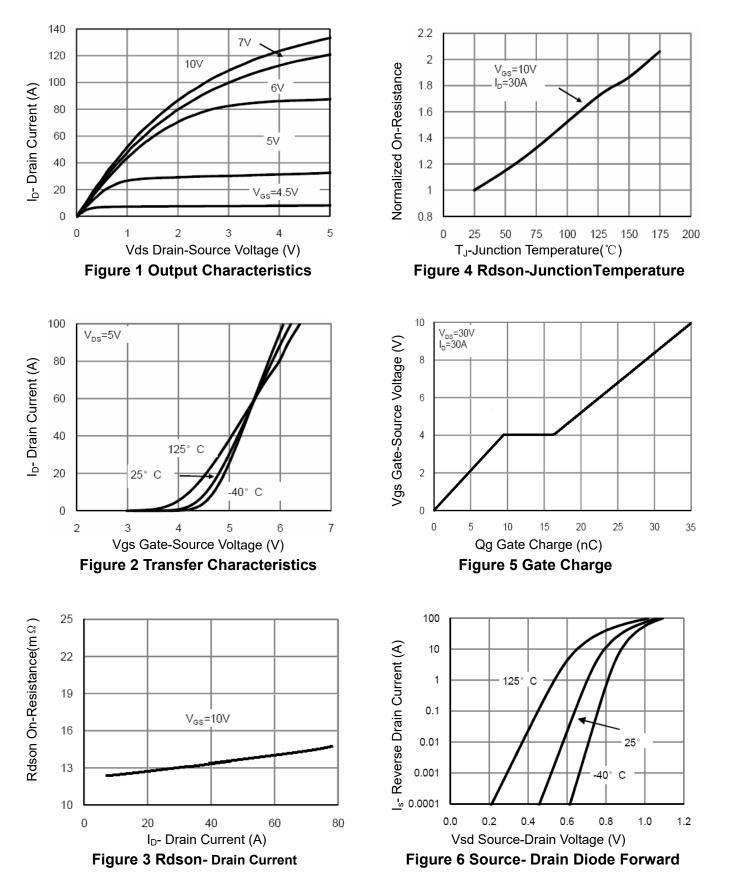
2. Surface Mounted on FR4 Board, $t \le 10$ sec.

3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

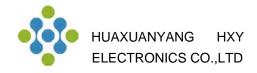
4. Guaranteed by design, not subject to production

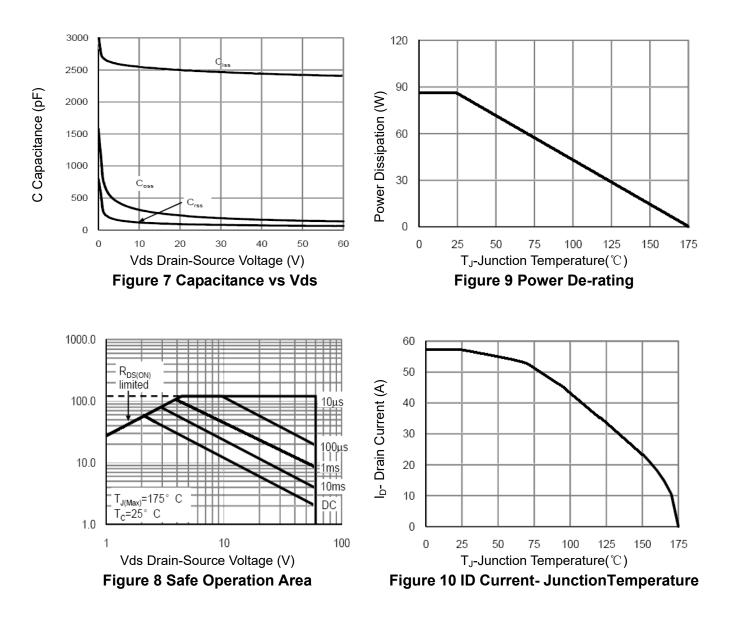
5. E_{AS} condition: Tj=25 $^\circ \!\! ^\circ \!\!$

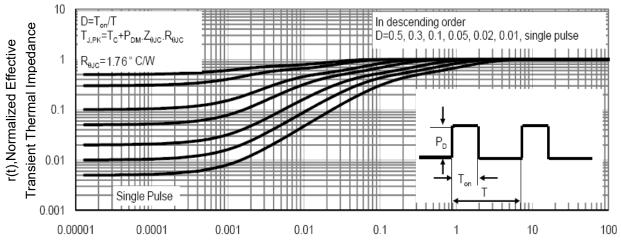


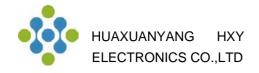


Typical Electrical and Thermal Characteristics (Curves)

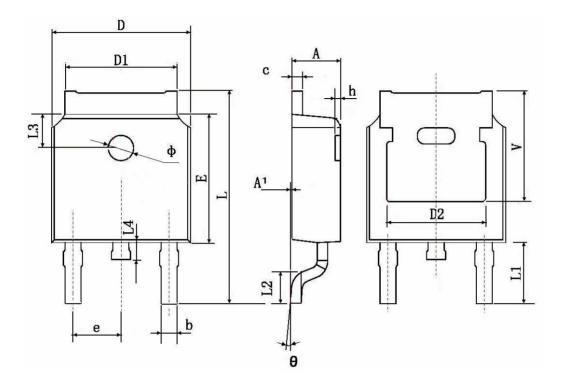








TO-252-2L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
A	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
с	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	0.483 TYP.		0.190 TYP.		
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900 TYP.		0.114 TYP.		
L2	1.400	1.700	0.055	0.067	
L3	1.600	1.600 TYP.		0.063 TYP.	
L4	0.600	1.000	0.024	0.039	
Φ	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350 TYP.		0.211 TYP.		



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